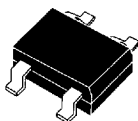


CBR1-D020S SERIES

1.0 AMP DUAL IN LINE BRIDGE RECTIFIER



SMDIP CASE

CentralTM
Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CBR1-D020S series types are silicon full wave bridge rectifiers mounted in a durable epoxy, surface mount, molded case, utilizing glass passivated chips. To order devices on tape and reel (1,000/13" reel) add TR13 suffix.

NOTE: Also available in Fast Recovery, please contact factory for details.

MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$)

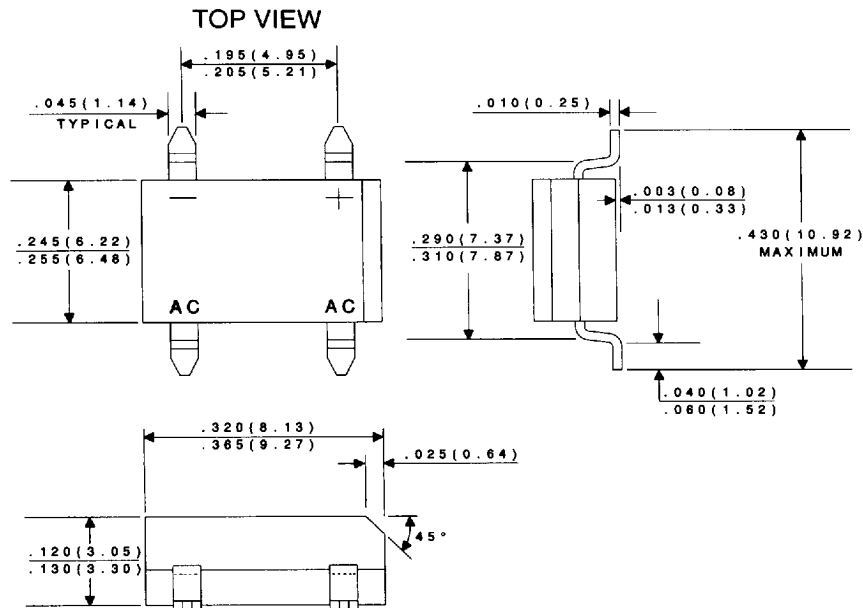
	SYMBOL	CBR1- D020S	CBR1- D040S	CBR1- D060S	CBR1- D100S	UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	200	400	600	1000	V
DC Blocking Voltage	V_R	200	400	600	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	140	280	420	700	V
Average Forward Current ($T_A=50^{\circ}\text{C}$)	I_O		1.0			A
Peak Forward Surge Current	I_{FSM}		50			A
Operating and Storage						
Junction Temperature	T_J, T_{stg}		-65 to +150			$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
V_F	$I_F=1.0\text{A}$			1.1	V
I_R	$V_R=\text{Rated } V_{RRM}$			10	μA
I_R	$V_R=\text{Rated } V_{RRM}, T_A=125^{\circ}\text{C}$			0.5	mA
C_J	$V_R=4.0\text{V}, f=1.0\text{MHz}$		25		pF

1989963 0001721 T04 70

All dimensions in inches (mm).



DATA
SHEET

R2